

2MBI225VN-120-50

IGBT Modules

IGBT MODULE (V series) 1200V / 225A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
Collector-Emi	tor-Emitter voltage V _{CES}		1200	V			
Gate-Emitter	voltage	V _{GES}			±20	V	
te	Collector current		Continuous	Tc=80°C	225		
Ö Collector our			1ms	Tc=80°C	450	^	
S Collector curr	rent	-lc				Α	
_			1ms		450		
Collector power dissipation		Pc	1 device	1 device		W	
Junction temperature		Tj			175		
Operating junction temperature (under switching conditions)		Tjop			150	°C	
Case temperature		Tc			125	C	
Storage temperature		Tstg					
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	Viso	AC : 1min.	AC : 1min.		VAC	
Screw torque	Mounting (*3)				3.5	N m	
	Terminals (*4)]-			4.5	IN III	

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value : Mounting : 2.5-3.5 Nm (M5) Note *4: Recommendable value : Terminals : 3.5-4.5 Nm (M6)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items		Cympholo	Conditions		Characteristics		Units	
		Symbols			min.	typ.	max.	Units
	Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	3.0	mA
	Gate-Emitter leakage current	Iges	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	600	nA
	Gate-Emitter threshold voltage	nitter threshold voltage V _{GE (th)} V _{CE} = 20V, I _C = 225mA			6.0	6.5	7.0	V
Inverter	Collector-Emitter saturation voltage	V _{CE (sat)} (terminal)	V _{GE} = 15V I _C = 225A	Tj=25°C	-	2.20	2.65	V
				Tj=125°C	-	2.55	-	
				Tj=150°C	-	2.60	-	
		V _{CE (sat)} (chip)		Tj=25°C	-	1.85	2.30	
				Tj=125°C	-	2.20	-	
				Tj=150°C	-	2.25	-	
	Input capacitance	Cies	$V_{CE} = 10V$, $V_{GE} = 0V$, $f = 1MHz$		-	18	-	nF
	Turn-on time	ton	V _{cc} = 600V		-	550	1200	
		tr Vcc - 600V c = 225A		-	180	600]	
		tr (i)	$V_{GE} = \pm 15V$ $R_{G} = 1.6\Omega$		-	120	-	nsec
	Turn-off time	toff			-	1050	2000	
		tf			-	110	350	
	Forward on voltage	V₅ (terminal)		Tj=25°C	-	2.05	2.50	V
				Tj=125°C	-	2.20	-	
		(terrillial)	$V_{GE} = 0V$	Tj=150°C	-	2.15		
		V _F (chip)	I _F = 225A	Tj=25°C	-	1.70	2.15	
				Tj=125°C	-	1.85	-	
				Tj=150°C	-	1.80	-	
	Reverse recovery time	trr	I _F = 225A		-	200	600	nsec
stor	Resistance	R	T=25°C		-	5000	-	Ω
Thermistor	1/63/3(a)/6		T=100°C		465	495	520	
Ē	B T=25/50°C			3305	3375	3450	K	

Thermal resistance characteristics

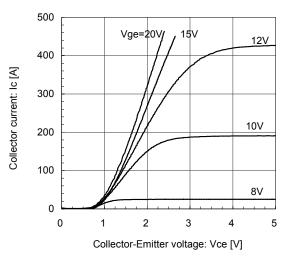
Items	Symbols	Conditions	Characteristics			Units
items			min.	typ.	max.	Ullits
Theymal registeres (4device)	Dth/i a)	Inverter IGBT	-	-	0.14	°C/W
Thermal resistance (1device)	Rth(j-c)	Inverter FWD	-	-	0.19	
Contact thermal resistance (1device) (*5)	Rth(c-f)	with Thermal Compound	-	0.0167	-	

Note *5: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

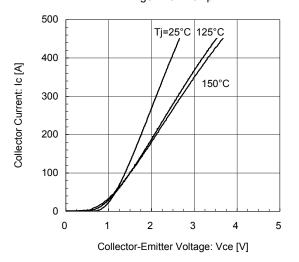
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Tj= 25°C / chip



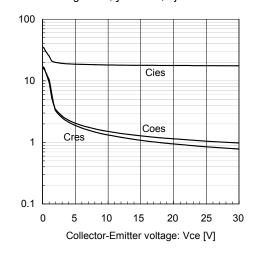
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Vge= 15V / chip



[INVERTER]

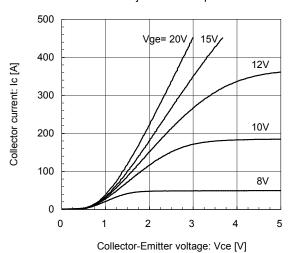
Gate Capacitance vs. Collector-Emitter Voltage (typ.) Vge= 0V, f= 1MHz, Tj= 25°C



Gate Capacitance: Cies, Coes, Cres [nF]

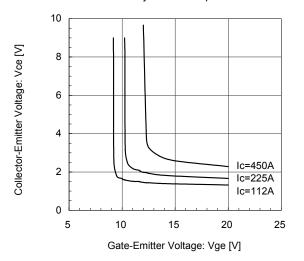
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip



[INVERTER]

Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) $Tj=25^{\circ}C$ / chip



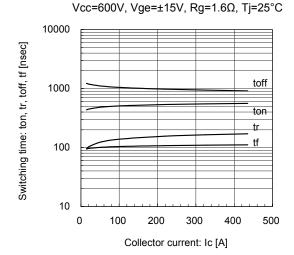
[INVERTER]

Dynamic Gate Charge (typ.) Vcc=600V, Ic=225A, Tj= 25°C

Collector-Emitter voltage: Vce [2000V/div]
Gate-Emitter voltage: Vge [5V/div]
O 500 1000 1500 2000

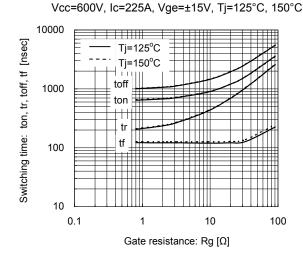
Gate charge: Qg [nC]

[INVERTER] Switching time vs. Collector current (typ.)

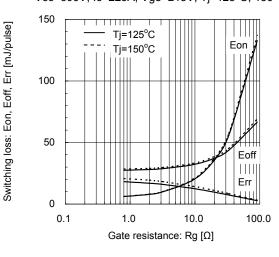


[INVERTER]

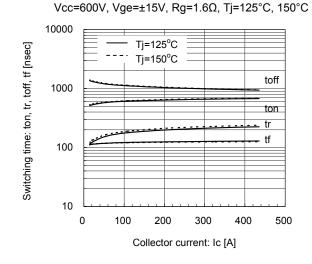
Switching time vs. Gate resistance (typ.)



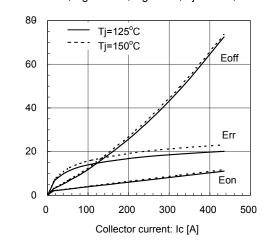
[INVERTER]
Switching loss vs. Gate resistance (typ.)
Vcc=600V, Ic=225A, Vge=±15V, Tj=125°C, 150°C



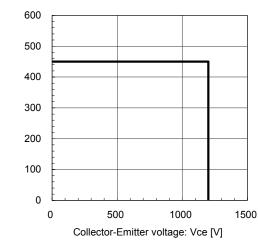
[INVERTER]
Switching time vs. Collector current (typ.)



[INVERTER]
Switching loss vs. Collector current (typ.)
Vcc=600, Vge=±15V, Rg=1.6Ω, Tj=125°C, 150°C



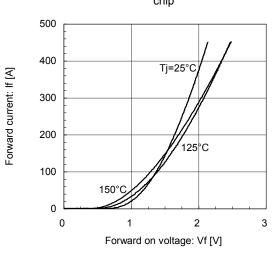
[INVERTER] Reverse bias safe operating area (max.) +Vge=15V, -Vge=15V, Rg=1.6 Ω , Tj=150°C



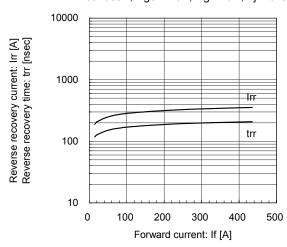
Switching loss: Eon, Eoff, Err [mJ/pulse]

Collector current: Ic [A]

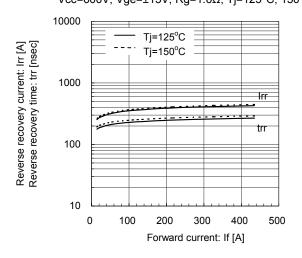
[INVERTER]
Forward Current vs. Forward Voltage (typ.)
chip



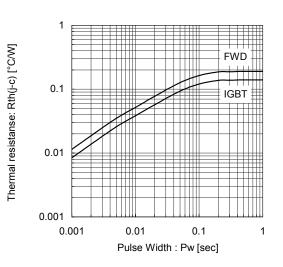
[INVERTER]
Reverse Recovery Characteristics (typ.)
Vcc=600V, Vge=±15V, Rg=1.6Ω, Tj=25°C



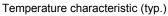
[INVERTER] Reverse Recovery Characteristics (typ.) Vcc=600V, Vge= \pm 15V, Rg=1.6 Ω , Tj=125°C, 150°C

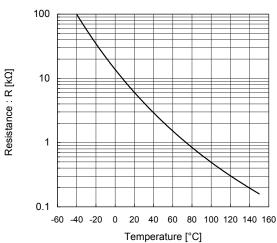


Transient Thermal Resistance (max.)

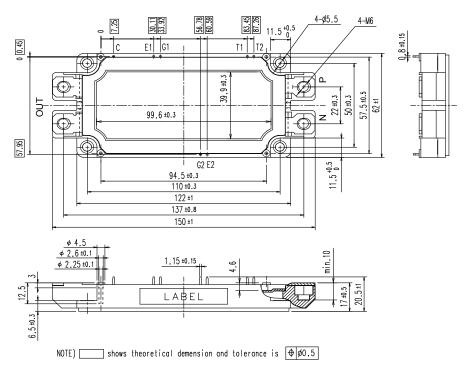


[THERMISTOR]

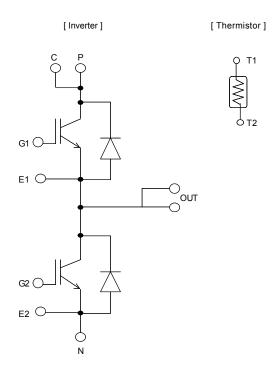




■ Outline Drawings, mm



■ Equivalent Circuit Schematic



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- Communications equipment (terminal devices)
- Measurement equipment

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- Audiovisual equipment
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- Personal equipment
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